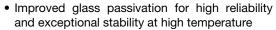


Medium Power Phase Control Thyristors (Stud Version), 10 A



| PRIMARY CHARACTERISTICS | | | | |
|------------------------------------|--|--|--|--|
| I _{T(AV)} | 10 A | | | |
| V _{DRM} /V _{RRM} | 100 V, 200 V, 400 V, 600 V, 800 V, 1000 V, 1200 V | | | |
| V _{TM} | 1.75 V | | | |
| I _{GT} | 60 mA | | | |
| T _J | -65 °C to +125 °C | | | |
| Package | TO-48 (TO-208AA) | | | |
| Circuit configuration | Single SCR | | | |

FEATURES





- High dl_F/dt and dV/dt capabilities
- Standard package
- Low thermal resistance
- · Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- Designed and qualified for industrial and consumer level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Medium power switching
- · Phase control applications

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|------------------------------------|-----------------|-------------|------------------|--|--|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS | | |
| 1 | | 10 | A | | |
| I _{T(AV)} | T _C | 85 | °C | | |
| I _{T(RMS)} | | 25 | A | | |
| I _{TSM} | 50 Hz | 225 | Α | | |
| | 60 Hz | 240 | | | |
| l²t | 50 Hz | 255 | A ² s | | |
| | 60 Hz | 233 | A-S | | |
| V _{DRM} /V _{RRM} | | 100 to 1200 | V | | |
| t _q | Typical | 110 | μs | | |
| T _J | | -65 to +125 | °C | | |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | | | |
|-----------------|-----------------|---|---|---|--|--|--|
| TYPE NUMBER | VOLTAGE CODE | V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V | I_{DRM}/I_{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA | | | |
| | 10 | 100 | 150 | 20 | | | |
| | 20 | 200 | 300 | | | | |
| | 40 | 400 | 500 | | | | |
| VS-10RIA | 60 | 600 | 700 | 10 | | | |
| | 80 | 800 | 900 | 10 | | | |
| | 100 | 1000 | 1100 | | | | |
| | 120 | 1200 | 1300 | | | | |

Notes

⁽¹⁾ Units may be broken over non-repetitively in the off-state direction without damage, if dl/dt does not exceed 20 A/µs

 $[\]ensuremath{^{(2)}}$ For voltage pulses with $t_p \leq 5 \ ms$



| ABSOLUTE MAXIMUM RAT | TINGS | | | | | |
|---|---------------------|--|--|-----------------------------|--------|--------------------|
| PARAMETER | SYMBOL | | TEST CONDITIONS | | VALUES | UNITS |
| Maximum average on-state current | I | 190° conducti | 180° conduction, half sine wave | | 10 | Α |
| at case temperature | I _{T(AV)} | 100 Conducti | on, nan sine wave | | 85 | °C |
| Maximum RMS on-state current | I _{T(RMS)} | | | | 25 | Α |
| | | t = 10 ms | No voltage | | 225 | |
| Maximum peak, one-cycle | L | t = 8.3 ms | reapplied | | 240 | Α |
| non-repetitive surge current | I _{TSM} | t = 10 ms | 100 % V _{RRM} | | 190 | A A ² s |
| | | t = 8.3 ms | reapplied | Sinusoidal half wave, | 200 | |
| Maximum I ² t for fusing | | t = 10 ms | No voltage | initial $T_J = T_J$ maximum | 255 | |
| | l ² t | t = 8.3 ms | reapplied | | 233 | |
| | i-r | t = 10 ms 100 % | 100 % V _{RRM} | | 180 | |
| | | t = 8.3 ms | reapplied | | 165 | |
| Maximum I ² √t for fusing | I²√t | t = 0.1 to 10 ms, no voltage reapplied | | 2550 | A²√s | |
| Low level value of threshold voltage | V _{T(TO)1} | (16.7 % x π x | (16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum | | 1.10 | V |
| High level value of threshold voltage | V _{T(TO)2} | $(I > \pi \times I_{T(AV)}),$ | $T_J = T_J \text{ maximum}$ | | 1.39 | V |
| Low level value of on-state slope resistance | r _{t1} | (16.7 % x π x | (16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum | | 24.3 | mΩ |
| High level value of on-state slope resistance | r _{t2} | $(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$ | | | 16.7 | 11152 |
| Maximum on-state voltage | V_{TM} | I_{pk} = 32 A, T_J = 25 °C, t_p = 10 ms sine pulse | | 1.75 | V | |
| Maximum holding current | I _H | T. = 25 °C 22 | odo supply 12 V ro | esistivo load | 130 | mA |
| Typical latching current | ΙL | 1j = 25 C, all | ode supply 12 V re | SISTING TOAU | 200 | mA |

| SWITCHING | | | | | |
|--|-----------------------------|---------------------|---|--------|--------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| | $V_{DRM} \le 600 \text{ V}$ | | | 200 | |
| $\begin{array}{ll} \text{Maximum rate of rise} & \hline V_{DRM} \leq 800 \text{ V} \\ \text{of turned-on current} & \hline V_{DRM} \leq 1000 \text{ V} \\ \hline V_{DRM} \leq 1600 \text{ V} \\ \end{array}$ | | 41 /d+ | $\begin{array}{c} T_J = T_J \text{ maximum, } V_{DM} = \text{Rated } V_{DRM} \\ \text{dI}_F/\text{dt} & \text{Gate pulse} = 20 \text{ V, } 15 \Omega, t_p = 6 \text{ µs, } t_r = 0.1 \text{ µs maximum} \\ I_{TM} = (2 \text{ x rated dI/dt) A} \end{array}$ | 180 | - A/μs |
| | | ai _F /ai | | 160 | |
| | | - | , | 150 | |
| Typical turn-on time | | t _{gt} | $T_J = 25$ °C, at rated V_{DRM}/V_{RRM} , $T_J = 125$ °C | 0.9 | |
| Typical reverse recovery time | | t _{rr} | $T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$, $t_p > 200 \mu s$, $dI_F/dt = -10 A/\mu s$ | 4 | μs |
| Typical turn-off time | | tq | $T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$, $t_p > 200~\mu$ s, $V_R = 100~V$, $dI_F/dt = -10~A/\mu$ s, $dV/dt = 20~V/\mu$ s linear to 67 % V_{DRM} , gate bias 0 V to 100 W | 110 | μο |

Note

• $t_q = 10 \mu s$ up to 600 V, $t_q = 30 \mu s$ up to 1600 V available on special request

| BLOCKING | | | | |
|-------------------------------|--------|---|---------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum critical rate of rise | dV/dt | $T_J = T_J$ maximum linear to 100 % rated V_{DRM} | 100 | V/µs |
| of off-state voltage | uv/ut | $T_J = T_J$ maximum linear to 67 % rated V_{DRM} | 300 (1) | ν/μ5 |

Note

 $^{(1)}$ Available with: $dV/dt = 1000 V/\mu s$, to complete code add S90 i.e. 10RIA120S90



| TRIGGERING | | | | | |
|-------------------------------------|--------------------|---|---|--------|-------|
| PARAMETER | SYMBOL | TE | ST CONDITIONS | VALUES | UNITS |
| Maximum peak gate power | P _{GM} | T - T movimum | | 8.0 | W |
| Maximum average gate power | P _{G(AV)} | $T_J = T_J$ maximum | | 2.0 | ۷V |
| Maximum peak positive gate current | I_{GM} | $T_J = T_J$ maximum | | 1.5 | Α |
| Maximum peak negative gate voltage | -V _{GM} | $T_J = T_J$ maximum | | 10 | V |
| | I _{GT} | T _J = -65 °C | Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied | 90 | mA |
| DC gate current required to trigger | | T _J = 25 °C | | 60 | |
| | | T _J = 125 °C | | 35 | |
| | V _{GT} | T _J = -65 °C | | 3.0 | V |
| DC gate voltage required to trigger | | T _J = 25 °C | | 2.0 | |
| | | T _J = 125 °C | | 1.0 | |
| DC gate current not to trigger | I_{GD} | T _J = T _J maximum, V _{DRM} = Rated value | | 2.0 | mA |
| DC gate voltage not to trigger | V_GD | $T_J = T_J$ maximum, $V_{DRM} = Rated value$ | Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied | 0.2 | V |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | |
|--|-----------------------------------|---|-------------|--------------|----------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VAL | VALUES | |
| Maximum operating junction and storage temperature range | T _J , T _{Stg} | | -65 to | +125 | °C |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation | 1. | 1.85 | |
| Maximum thermal resistance, case to heat sink | R _{thCS} | Mounting surface, smooth, flat and greased 0.35 | | 35 | K/W |
| | | | TO NUT | TO DEVICE | |
| | | | 20 (27.5) | 25 | lbf ⋅ in |
| Mounting torque | | Lubricated threads (Non-lubricated threads) | 0.23 (0.32) | 0.29 | kgf · m |
| | | (1011) (1211) (111) | 2.3 (3.1) | 2.8 | N · m |
| Approximate weight | | 14 | | 4 | g |
| Approximate weight | | | 0. | 49 | OZ. |
| Case style | | See dimensions - link at the end of datasheet | TO | -48 (TO-208A | A) |

| △R _{thJC} CONDUCTION | | | | |
|-------------------------------|-----------------------|------------------------|---------------------|-------|
| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | RECTANGULAR CONDUCTION | TEST CONDITIONS | UNITS |
| 180° | 0.44 | 0.32 | | |
| 120° | 0.53 | 0.56 | | |
| 90° | 0.68 | 0.75 | $T_J = T_J$ maximum | K/W |
| 60° | 1.01 | 1.05 | | |
| 30° | 1.71 | 1.73 | | |

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



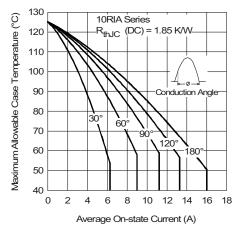


Fig. 1 - Current Ratings Characteristics

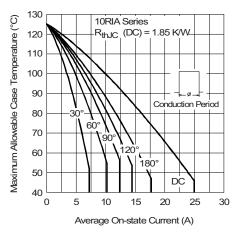


Fig. 2 - Current Ratings Characteristics

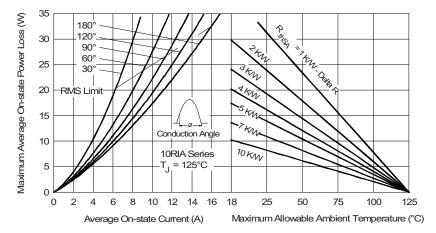


Fig. 3 - On-State Power Loss Characteristics

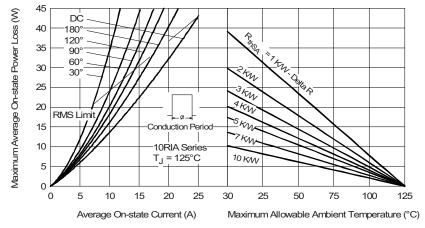


Fig. 4 - On-State Power Loss Characteristics



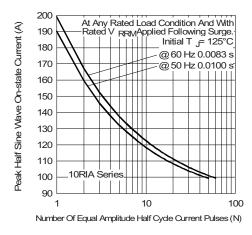


Fig. 5 - Maximum Non-Repetitive Surge Current

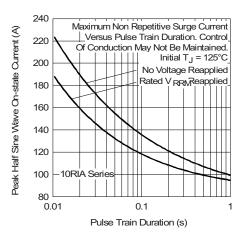


Fig. 6 - Maximum Non-Repetitive Surge Current

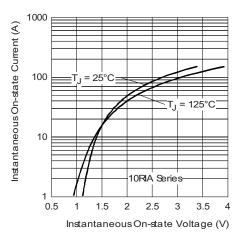


Fig. 7 - Forward Voltage Drop Characteristics

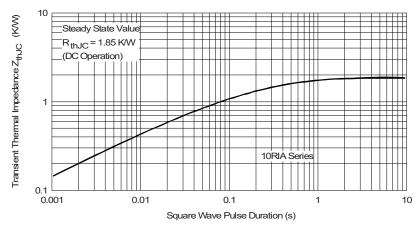


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



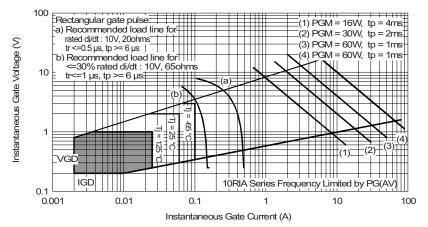
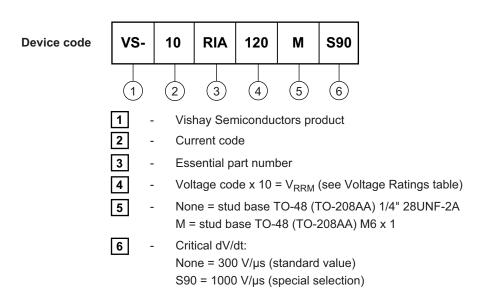


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

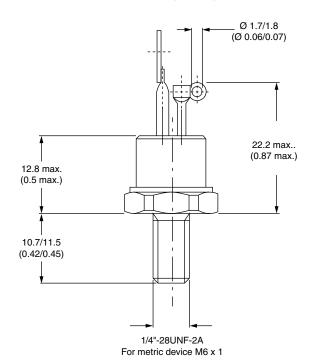


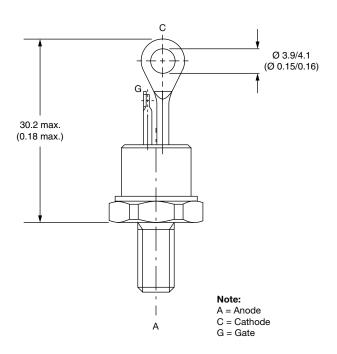
| LINKS TO RELAT | ED DOCUMENTS |
|----------------|--------------------------|
| Dimensions | www.vishay.com/doc?95333 |

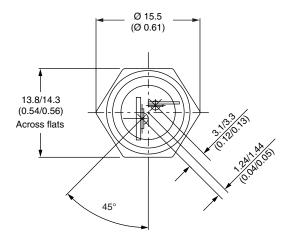


TO-208AA (TO-48)

DIMENSIONS in millimeters (inches)









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